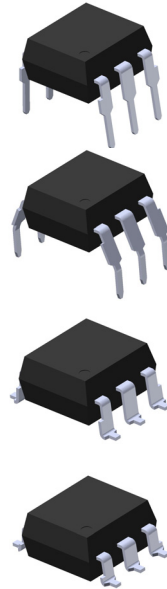


6 PIN DIP PHOTOTRANSISTOR PHOTOCOUPLER

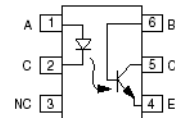
CNY17-X Series CNY17F-X Series

Features

- Current transfer ratios in selected narrow range groups
CNY17-1, CNY17F-1: 40-80%
CNY17-2, CNY17F-2: 63-125%
CNY17-3, CNY17F-3: 100-200%
CNY17-4, CNY17F-4: 160-320%
- High isolation voltage between input and output
(Viso = 5000 Vrms)
- Creepage distance > 7.6 mm
- Operating temperature up to +110°C
- The CNY17F-X series offers no external base connection for minimum noise susceptibility
- Compact dual-in-line package
- Pb free and RoHS compliant.
- UL approved (No. E214129)
- VDE approved (No. 132249)
- SEMKO approved
- NEMKO approved
- DEMKO approved
- FIMKO approved
- CSA approved

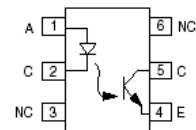


Schematic



CNY17-X

1. Anode
2. Cathode
3. No Connection
4. Emitter
5. Collector
6. Base



CNY17F-X

1. Anode
2. Cathode
3. No Connection
4. Emitter
5. Collector
6. No Connection

Description

The CNY17-X and CNY17F-X series of devices each consist of an infrared emitting diode optically coupled to a phototransistor.

It is packaged in a 6-pin DIP package and available in wide-lead spacing and SMD option.

Applications

- Power supply regulators
- Digital logic inputs
- Microprocessor inputs

6 PIN DIP PHOTOTRANSISTOR PHOTOCOUPLER

CNY17-X Series CNY17F-X Series

Absolute Maximum Ratings (T_a=25°C)

Parameter		Symbol	Rating	Unit
Input	Forward current	I _F	60	mA
	Peak forward current (t = 10μs)	I _{FM}	1	A
	Reverse voltage	V _R	6	V
	Power dissipation (T _A = 25°C)	P _D	100	mW
	Derating factor (above 100°C)		3.8	mW/°C
Output	Collector-Emitter voltage	V _{CEO}	80	V
	Collector-Base voltage* ¹	V _{CBO}	80	V
	Collector current	I _C	50	mA
	Emitter-Collector voltage	V _{ECO}	7	V
	Power dissipation (T _A = 25°C)	P _C	150	mW
	Derating factor (above 100°C)		9.0	mW/°C
Total power dissipation		P _{tot}	200	mW
Isolation voltage * ²		V _{iso}	5000	V _{rms}
Operating temperature		T _{opr}	-55~+110	°C
Storage temperature		T _{stg}	-55~+125	°C
Soldering temperature * ³		T _{sol}	260	°C

Notes

*1 Only for CNY17-X series.

*2 AC for 1 minute, R.H.= 40 ~ 60% R.H. In this test, pins 1, 2 & 3 are shorted together, and pins 4, 5 & 6 are shorted together.

*3 For 10 seconds.

6 PIN DIP PHOTOTRANSISTOR PHOTOCOUPLER

CNY17-X Series CNY17F-X Series

Electrical Characteristics ($T_a=25^{\circ}\text{C}$ unless specified otherwise)

Input

Parameter	Symbol	Min.	Typ.*	Max.	Unit	Condition
Forward voltage	V_F	-	-	1.65	V	$I_F = 60\text{mA}$
Reverse current	I_R	-	-	10	μA	$V_R = 6\text{V}$
Input capacitance	C_{in}	-	18	-	pF	$V = 0, f = 1\text{MHz}$

Output

Parameter	Symbol	Min.	Typ.*	Max.	Unit	Condition
Collector-Base dark current	I_{CBO}	-	-	20	nA	$V_{CB} = 10\text{V}, I_F = 0\text{mA}$
Collector-Emitter dark current	I_{CEO}	-	-	50	nA	$V_{CE} = 10\text{V}, I_F = 0\text{mA}$
Collector-Emitter breakdown voltage	BV_{CEO}	80	-	-	V	$I_C = 1\text{mA}, I_F = 0\text{mA}$
Collector-Base breakdown voltage	BV_{CBO}	80	-	-	V	$I_C = 0.1\text{mA}, I_F = 0\text{mA}$
Emitter-Collector breakdown voltage	BV_{ECO}	7	-	-	V	$I_E = 0.1\text{mA}, I_F = 0\text{mA}$
Collector-Emitter capacitance	C_{CE}	-	8	-	pF	$V_{CE} = 0\text{V}, f = 1\text{MHz}$

* Typical values at $T_a = 25^{\circ}\text{C}$

6 PIN DIP PHOTOTRANSISTOR PHOTOCOUPLER

CNY17-X Series CNY17F-X Series

Transfer Characteristics ($T_a=25^{\circ}\text{C}$ unless specified otherwise)

Parameter		Symbol	Min.	Typ.*	Max.	Unit	Condition
Current Transfer Ratio	CNY17-1 CNY17F-1	CTR	40	-	80	%	$I_F = 10\text{mA}$, $V_{CE} = 5\text{V}$
	CNY17-2 CNY17F-2		63	-	125		
	CNY17-3 CNY17F-3		100	-	200		
	CNY17-4 CNY17F-4		160	-	320		
Current Transfer Ratio	CNY17-1 CNY17F-1	CTR	13	-	-	%	$I_F = 1\text{mA}$, $V_{CE} = 5\text{V}$
	CNY17-2 CNY17F-2		22	-	-		
	CNY17-3 CNY17F-3		34	-	-		
	CNY17-4 CNY17F-4		56	-	-		
Collector-Emitter saturation voltage		$V_{CE(sat)}$	-	-	0.3	V	$I_F = 10\text{mA}$, $I_C = 2.5\text{mA}$
Isolation resistance		R_{IO}	10^{11}	-	-	Ω	$V_{IO} = 500\text{Vdc}$
Input-output capacitance		C_{IO}	-	0.5	-	pF	$V_{IO} = 0$, $f = 1\text{MHz}$
Turn-on time		T_{on}	-	10	12	μs	$V_{CC} = 10\text{V}$, $I_C = 2\text{mA}$, $R_L = 100\Omega$ See Fig. 11
Turn-off time		T_{off}	-	9	12		
Rise time		T_r	-	6	10		
Fall time		T_f	-	8	10		
Rise time		T_r	-	2	10		$V_{CC} = 5\text{V}$, $I_F = 10\text{mA}$, $R_L = 75\Omega$, See Fig. 11
Fall time		T_f	-	3	10		

* Typical values at $T_a = 25^{\circ}\text{C}$

6 PIN DIP PHOTOTRANSISTOR PHOTOCOUPLER

CNY17-X Series CNY17F-X Series

Typical Performance Curves

Figure 1. Forward Current vs Forward Voltage

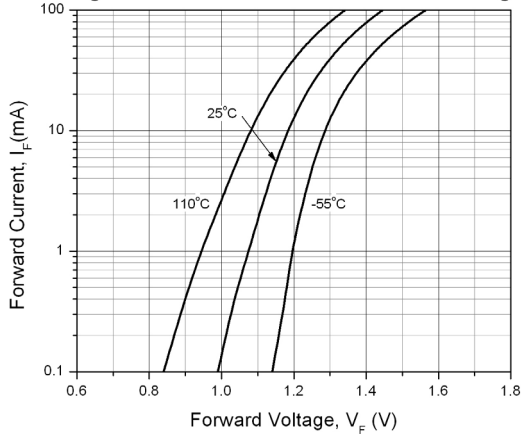


Figure 2. Current Transfer Ratio vs Forward Current

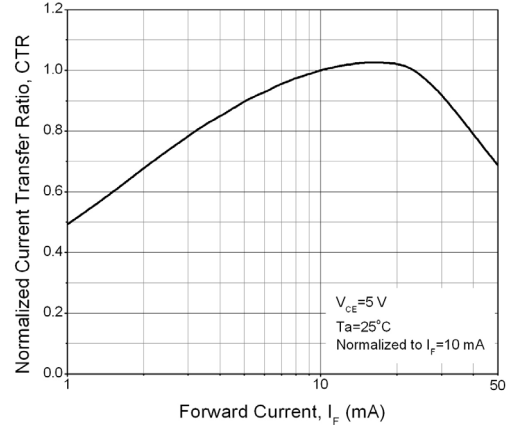


Figure 3. Current Transfer Ratio vs Ambient Temperature

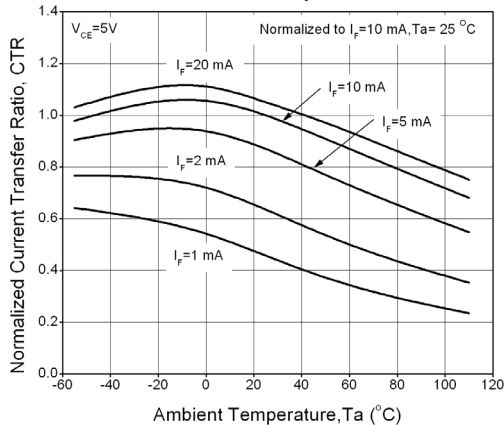


Figure 4. Current Transfer Ratio (Saturated) vs Base-Emitter Resistance

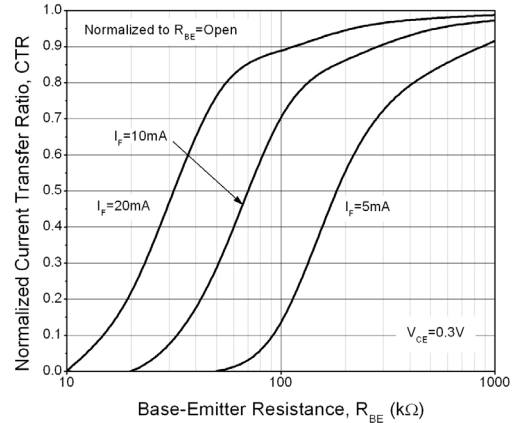


Figure 5. Current Transfer Ratio (Unsaturated) vs Base-Emitter Resistance

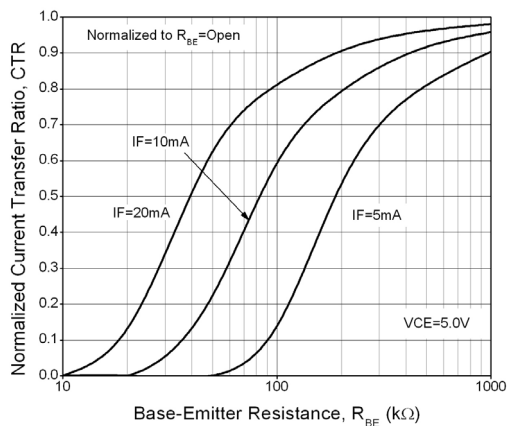
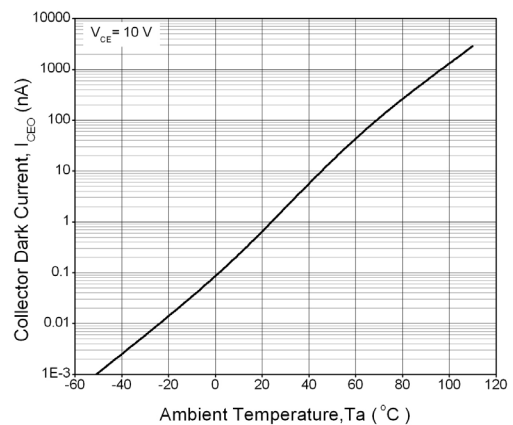


Figure 6. Dark Current vs Ambient Temperature



6 PIN DIP PHOTOTRANSISTOR PHOTOCOUPLER

CNY17-X Series CNY17F-X Series

Figure 7. Collector-Emitter Saturation Voltage vs Collector Current

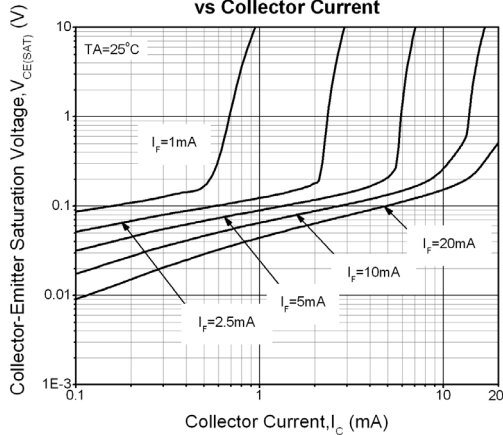


Figure 8. Switching Time vs Load Resistance

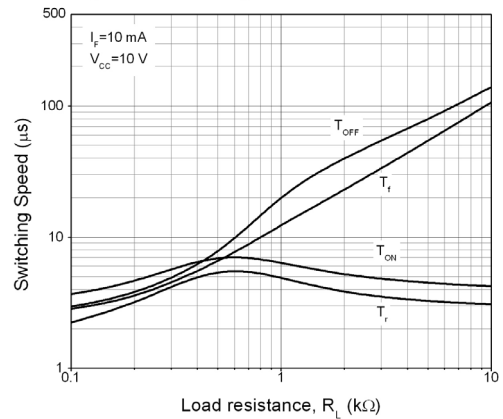


Figure 9. Turn-on Time vs Base-Emitter Resistance

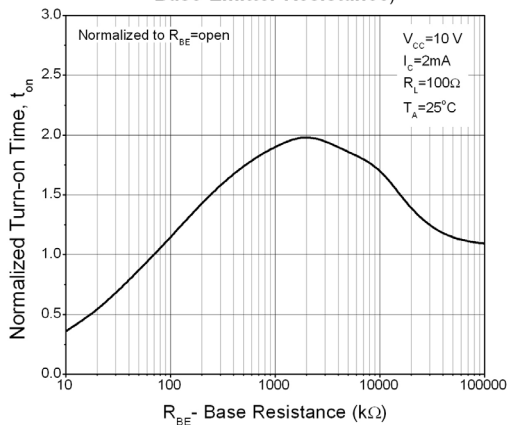


Figure 10. Turn-off Time vs Base-Emitter Resistance

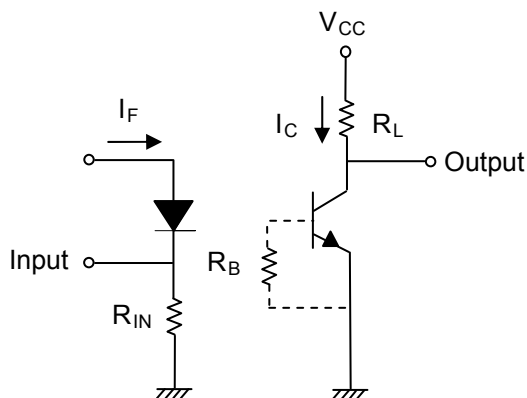
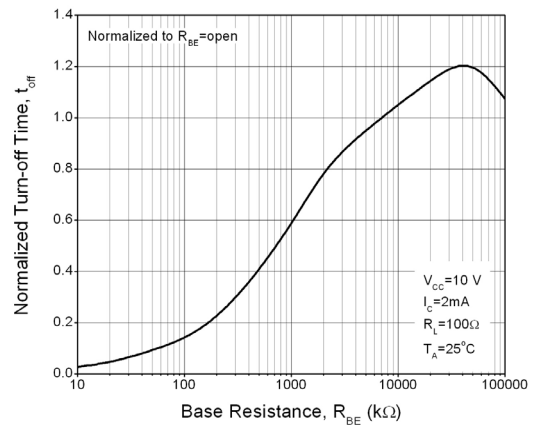


Figure 11. Switching Time Test Circuit & Waveforms

6 PIN DIP PHOTOTRANSISTOR PHOTOCOUPLER

**CNY17-X Series
CNY17F-X Series**

Order Information

Part Number

CNY17-XY(Z)-V

or

CNY17F-XY(Z)-V

Note

- X = Part no. (1, 2, 3 or 4)
- Y = Lead form option (S, S1, M or none)
- Z = Tape and reel option (TA, TB or none).
- V = VDE (optional)

Option	Description	Packing quantity
None	Standard DIP-6	65 units per tube
M	Wide lead bend (0.4 inch spacing)	65 units per tube
S (TA)	Surface mount lead form + TA tape & reel option	1000 units per reel
S (TB)	Surface mount lead form + TB tape & reel option	1000 units per reel
S1 (TA)	Surface mount lead form (low profile) + TA tape & reel option	1000 units per reel
S1 (TB)	Surface mount lead form (low profile) + TB tape & reel option	1000 units per reel

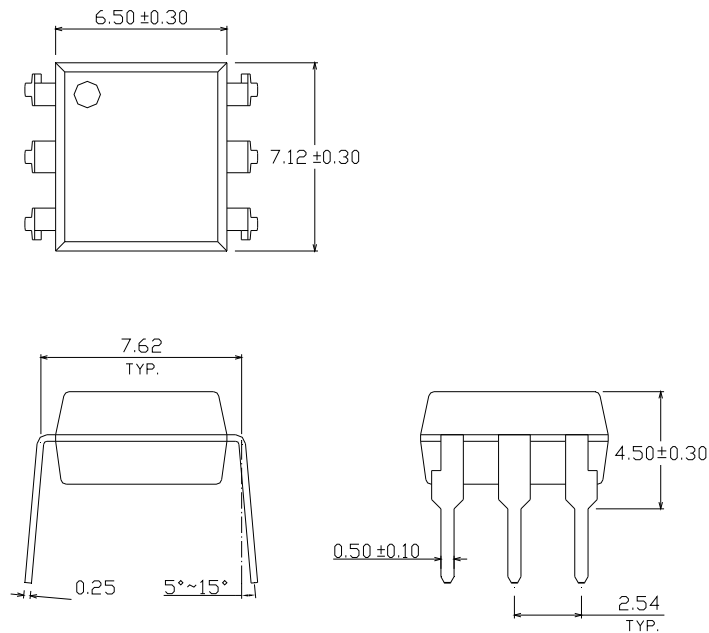
6 PIN DIP PHOTOTRANSISTOR PHOTOCOUPLER

**CNY17-X Series
CNY17F-X Series**

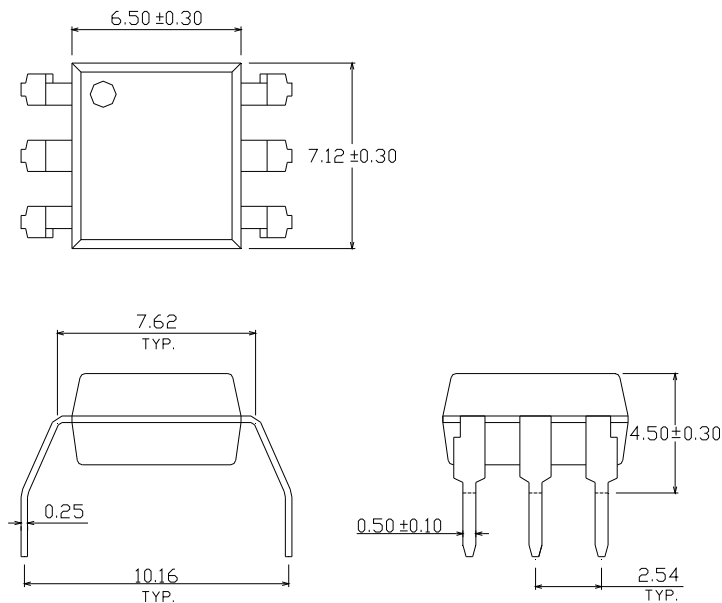
Package Drawings

(Dimensions in mm)

Standard DIP Type



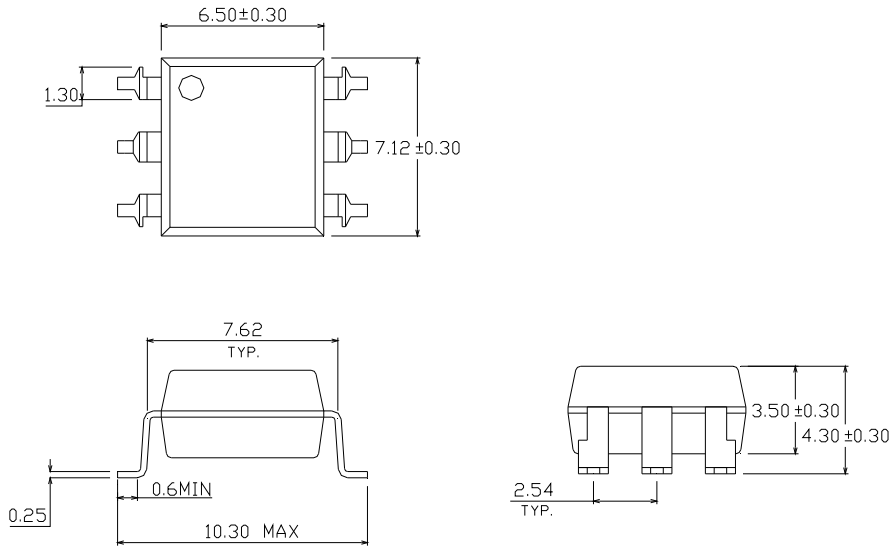
Option M Type



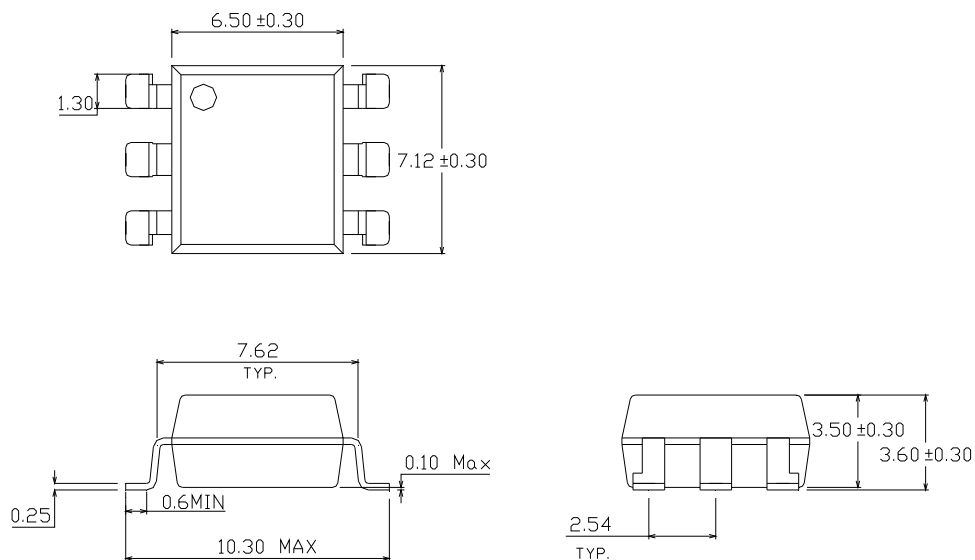
6 PIN DIP PHOTOTRANSISTOR PHOTOCOUPLER

**CNY17-X Series
CNY17F-X Series**

Option S Type



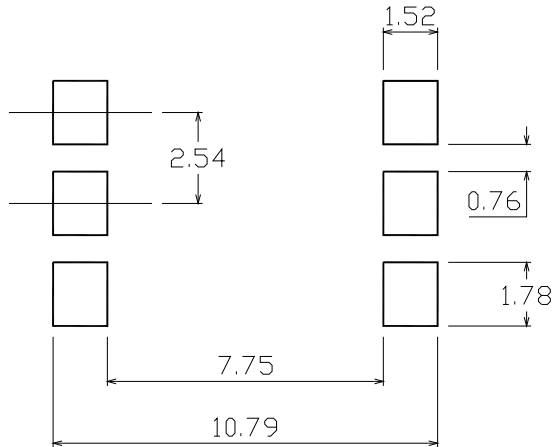
Option S1 Type



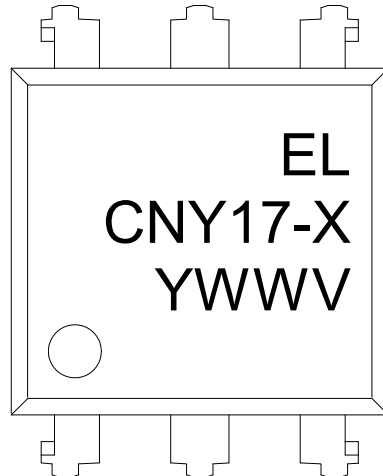
6 PIN DIP PHOTOTRANSISTOR PHOTOCOUPLER

**CNY17-X Series
CNY17F-X Series**

Recommended pad layout for surface mount leadform



Device Marking



Notes

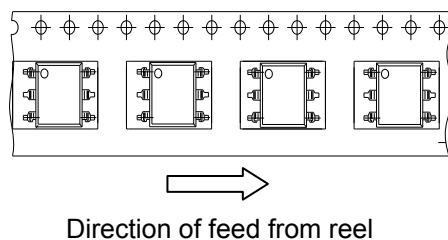
- EL denotes Everlight
- CNY17-X denotes Device Number (X: 1, 2, 3 or 4)
- Y denotes 1 digit Year code
- WW denotes 2 digit Week code
- V denotes VDE (optional)

6 PIN DIP PHOTOTRANSISTOR PHOTOCOUPLER

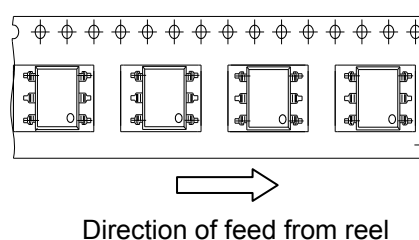
**CNY17-X Series
CNY17F-X Series**

Tape & Reel Packing Specifications

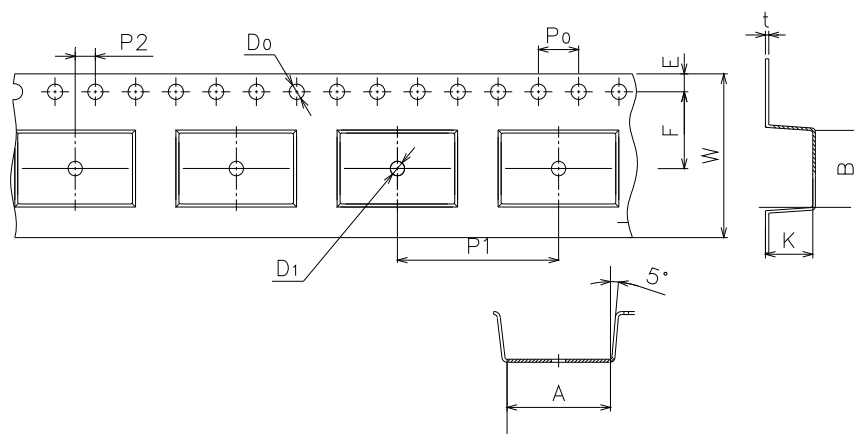
Option TA



Option TB



Tape dimensions



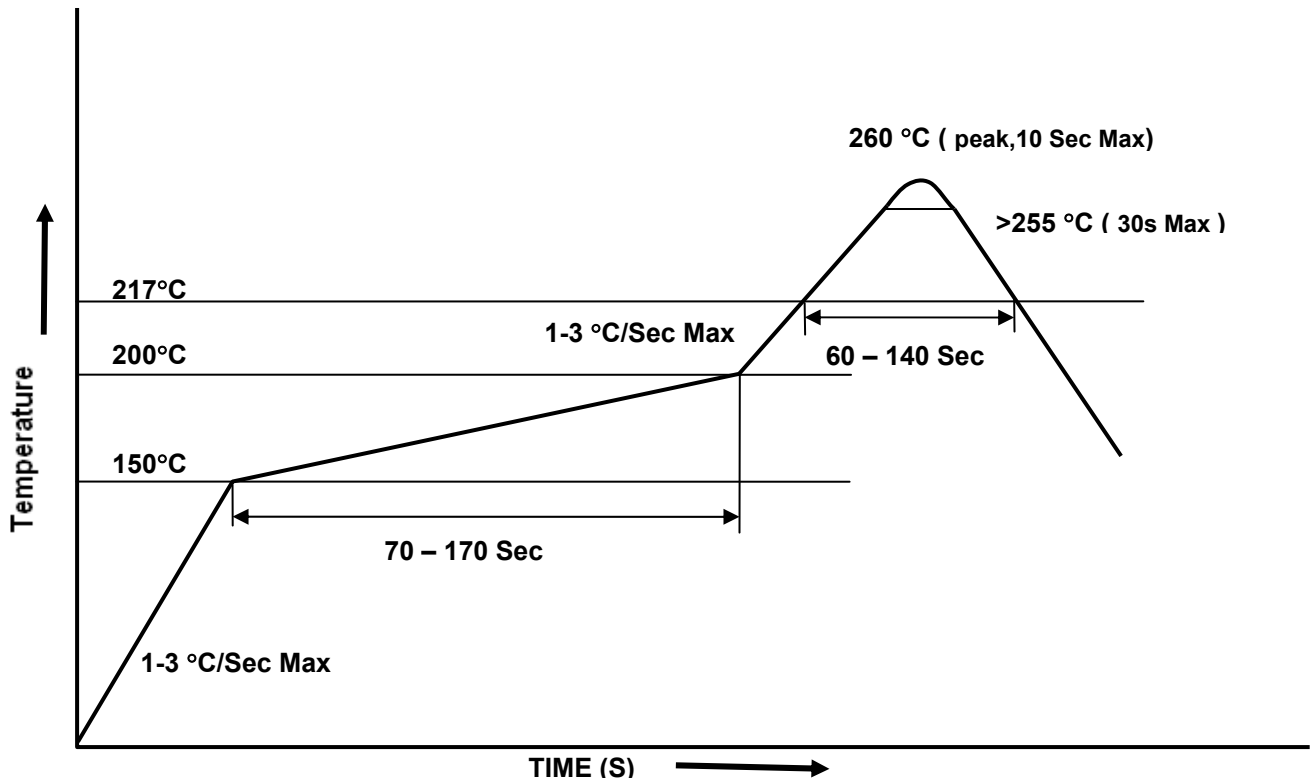
Dimension No.	A	B	Do	D1	E	F
Dimension (mm)	10.4±0.1	7.52±0.1	1.5±0.1	1.5+0.1/-0	1.75±0.1	7.5±0.1

Dimension No.	Po	P1	P2	t	W	K
Dimension (mm)	4.0±0.15	16.0±0.1	2.0±0.1	0.35±0.03	16.0±0.2	4.5±0.1

6 PIN DIP PHOTOTRANSISTOR PHOTOCOUPLER

**CNY17-X Series
CNY17F-X Series**

Solder Reflow Temperature Profile



6 PIN DIP PHOTOTRANSISTOR PHOTOCOUPLER

**CNY17-X Series
CNY17F-X Series**

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